NSN 5961-01-579-8567

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| Semiconductor Material: |
|---|
| Silicon |
| Voltage Rating In Volts Per Characteristic: |
| 80.0 collector to emitter voltage, $$ dc and 5.0 emitter to base voltage, $$ dc |
| Maximum Operating Tempurature Per Measurement Point: |
| 150.0 degrees celsius junction |
| Product Name: |
| Npn epitaxial silicon transistor |
| Special Features: |
| Low collector emitter saturation voltage |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Fiig: |